

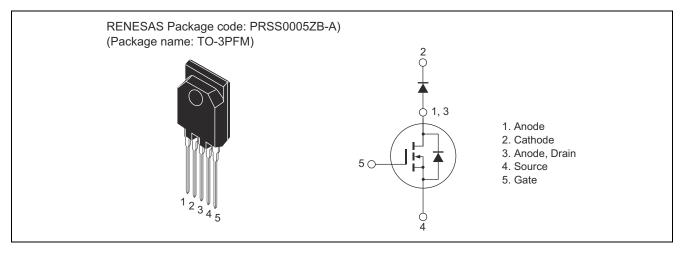
RJQ6020DPM

600V - 20A - MOS FET High Speed Power Switching R07DS0649EJ0100 Rev.1.00 Jan 23, 2012

Features

- High speed switching
- Low on-state voltage •
- Built in fast recovery diode in one package

Outline



Absolute Maximum Ratings

MOS FET

MOS FET	$(Ta = 25^{\circ}C)$		
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	600	V
Gate to source voltage	V _{GSS}	+30, -20	V
Drain current	I _D Note2	20	А
Drain peak current	I _{D(pulse)} Note1	40	А
Body-drain diode reverse drain current	I _{DR} Note2	20	А
Body-drain diode reverse drain peak current	Note1 I _{DR(pulse)}	40	А
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Limited by maximum safe operating area.

Diode				
ltem	Symbol	Ratings	Unit	
Maximum reverse voltage	V _{RM}	600	V	
Continuous forward current	I _F	10	A	
Peak surge forward current	I _{FSM}	20	A	
Junction temperature	Tj	150	۵°	
Storage temperature	Tstg	-55 to +150	٥°C	



Electrical Characteristics

MOS FET

 $(Ta = 25^{\circ}C)$ ltem Symbol Min Max Unit Test conditions Тур Drain to source breakdown voltage V_{(BR)DSS} 600 _ V $I_D = 10 \text{ mA}, \text{ } V_{GS} = 0$ _ 1 $V_{DS} = 600 \text{ V}, V_{GS} = 0$ Zero gate voltage drain current mΑ I_{DSS} — Gate to source leak current ±0.1 μΑ $V_{GS} = +30V, -20 V, V_{DS} = 0$ Igss _ _ V $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$ Gate to source cutoff voltage V_{GS(off)} 5 3 I_D = 15 A, V_{GS} = 10 V ^{Note3, 4} Static drain to source on state 0.100 0.125 Ω R_{DS(on)} _ resistance Input capacitance Ciss 2900 pF $V_{DS} = 25 V$ _ _ $V_{GS} = 0$ 3800 Output capacitance Coss pF ___ f = 100 kHz Reverse transfer capacitance Crss 4 pF _ _ $I_F = 30 \text{ A}, V_{GS} = 0^{Note3}$ 1.0 Body-drain diode forward voltage V_{DF} ___ 1.6 V

Notes: 3. Pulse test

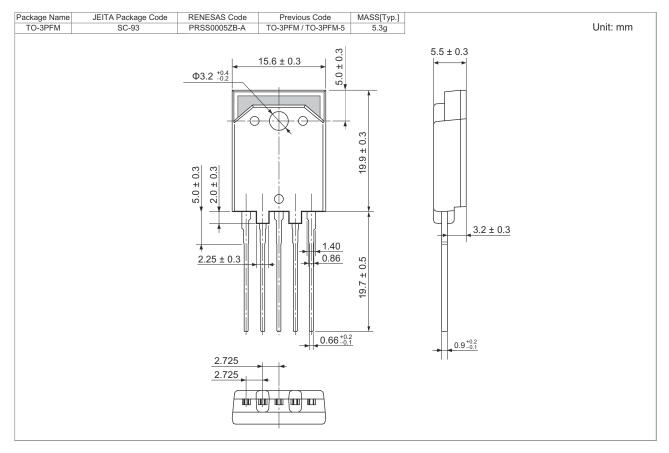
4. Value at pin 3 to pin 4.

Diode

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Forward voltage	VF	—	1.5	2.0	V	I _F = 10 A
Reverse current	I _R	—		10	μΑ	V _R = 600 V
Reverse recovery time	t _{rr}	_	15	_	ns	$I_F = 10 \text{ A}, \text{ di/dt} = -300 \text{ A}/\mu \text{ s}$



Package Dimensions





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